

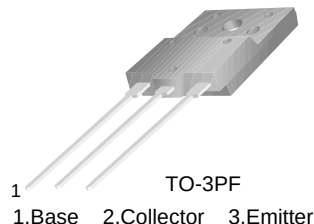
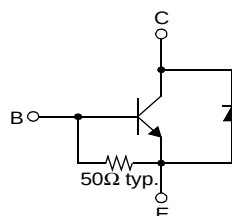
# KSD5702

KSD5702

## High Voltage Color Display Horizontal Deflection Output (Damper Diode Built In)

- High Collector-Base Voltage :  $V_{CBO}=1500V$
- High Switching Speed  $t_F = 0.4\mu s$  (Max.)
- For Color TV

Equivalent Circuit



## NPN Triple Diffused Planar Silicon Transistor

### Absolute Maximum Ratings $T_C=25^\circ C$ unless otherwise noted

| Symbol    | Parameter                                  | Value      | Units      |
|-----------|--------------------------------------------|------------|------------|
| $V_{CBO}$ | Collector-Base Voltage                     | 1500       | V          |
| $V_{CEO}$ | Collector-Emitter Voltage                  | 800        | V          |
| $V_{EBO}$ | Emitter-Base Voltage                       | 6          | V          |
| $I_C$     | Collector Current                          | 6          | A          |
| $I_{CP}$  | Collector Current (Pulse)                  | 16         | A          |
| $P_C$     | Collector Dissipation ( $T_C=25^\circ C$ ) | 60         | W          |
| $T_J$     | Junction Temperature                       | 150        | $^\circ C$ |
| $T_{STG}$ | Storage Temperature                        | - 55 ~ 150 | $^\circ C$ |

### Electrical Characteristics $T_C=25^\circ C$ unless otherwise noted

| Symbol        | Parameter                            | Test Condition                                                                   | Min. | Typ. | Max. | Units   |
|---------------|--------------------------------------|----------------------------------------------------------------------------------|------|------|------|---------|
| $I_{CBO}$     | Collector Cut-off Current            | $V_{CB} = 800V, I_E = 0$                                                         |      |      | 10   | $\mu A$ |
| $I_{EBO}$     | Emitter Cut-off Current              | $V_{EB} = 4V, I_C = 0$                                                           | 40   |      | 200  | mA      |
| $h_{FE1}$     | DC Current Gain                      | $V_{CE} = 5V, I_C = 1A$                                                          | 10   |      | 30   | -       |
| $h_{FE2}$     |                                      | $V_{CE} = 5V, I_C = 3A$                                                          | 5    |      | 15   |         |
| $V_{CE(sat)}$ | Collector-Emitter Saturation Voltage | $I_C = 4A, I_B = 0.8A$                                                           |      | 2    | 5    | V       |
| $V_{BE(sat)}$ | Base-Emitter Saturation Voltage      | $I_C = 4A, I_B = 0.8A$                                                           |      |      | 1.5  | V       |
| $f_T$         | Current Gain Bandwidth Product       | $V_{CE} = 10V, I_C = 1A$                                                         |      | 3    |      | MHz     |
| $V_F$         | Damper Diode Turn On Voltage         | $I_F = 6A$                                                                       |      |      | 2    | V       |
| $t_F$         | Fall Time                            | $V_{CC} = 200V, I_C = 4A$<br>$I_{B1} = 0.8A, I_{B2} = -1.6A$<br>$R_L = 50\Omega$ |      |      | 0.4  | $\mu s$ |

# Typical Characteristics

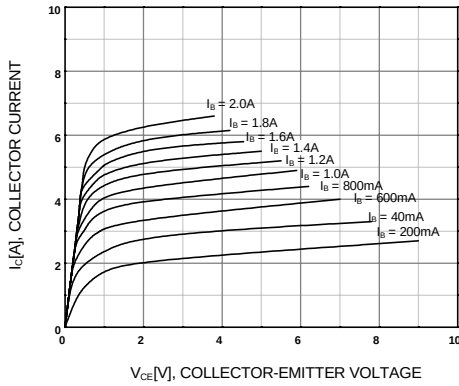


Figure 1. Static Characteristic

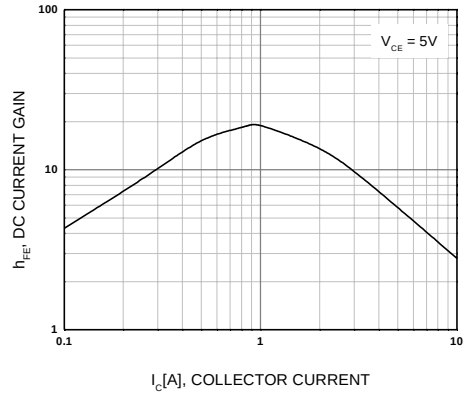


Figure 2. DC current Gain

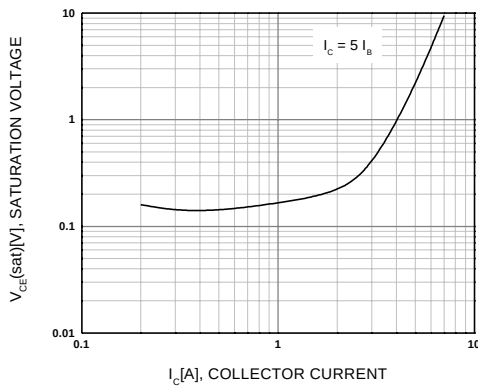


Figure 3. Collector-Emitter Saturation Voltage

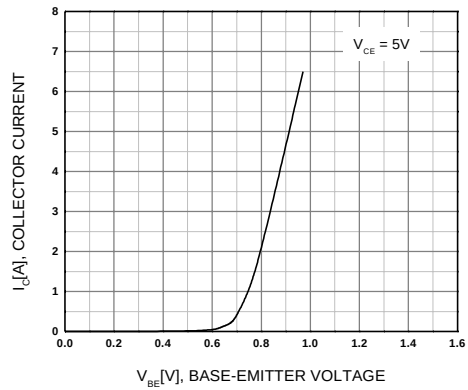


Figure 4. Base-Emitter On Voltage

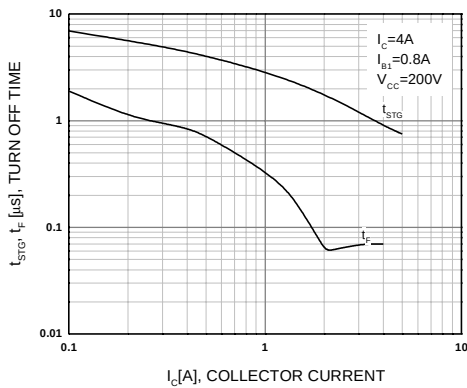


Figure 5. Switching Time

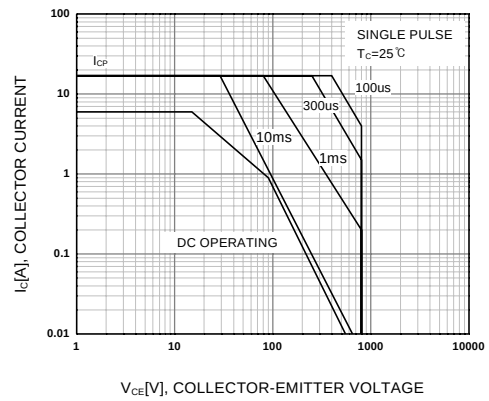


Figure 6. Safe Operating Area

## Typical Characteristics (Continued)

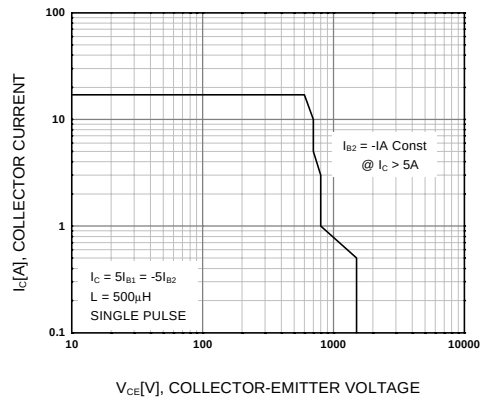


Figure 7. Reverse Bias Safe Operating Area

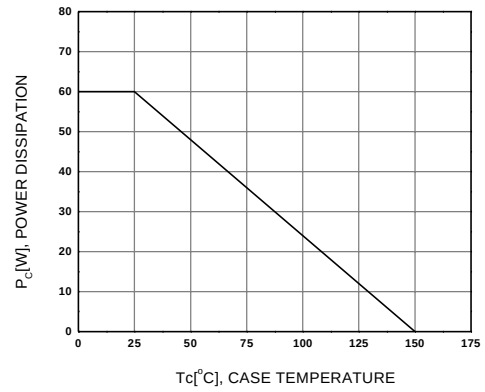
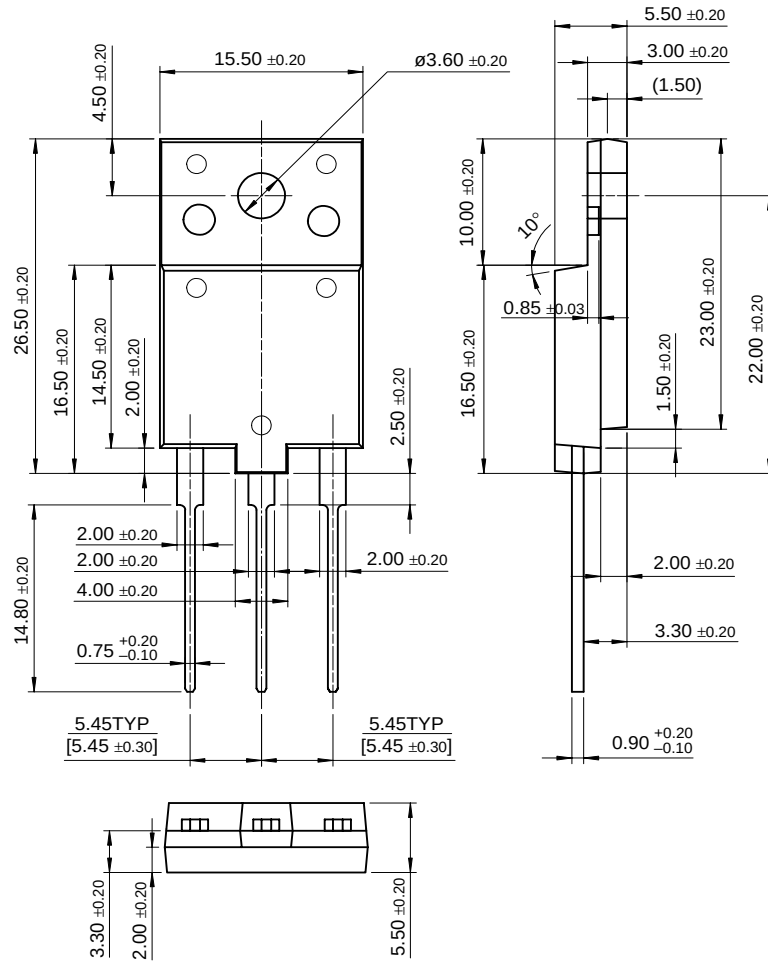


Figure 8. Power Derating

# Package Dimensions

## TO-3PF



Dimensions in Millimeters

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